HD74UH00

2-input NAND Gate

HITACHI

ADE-205-014A(Z) 2nd Edition August 1993

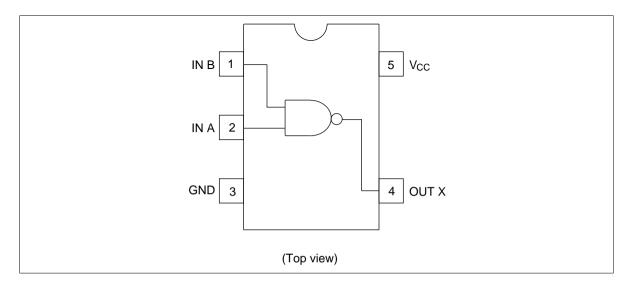
Description

The HD74UH00 is high speed CMOS two input NAND gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

- Encapsulated in very small 5pins package of 2.9 × 1.6 × 1.1 mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as hitachi uni logic series.
- Supplied on embos taping for high speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC00 Supply voltage range: 2 to 6 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$

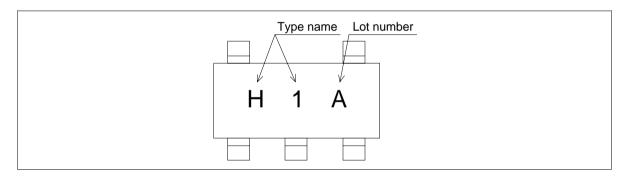
Pin Arrangement





HD74UH00

Article Indication



Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit |
|------------------------------|------------------------------------|------------------------------|------|
| Supply voltage | V _{cc} | -0.5 to +7.0 | V |
| Input voltage | V _{IN} | -0.5 to V _{cc} +0.5 | V |
| Output voltage | V _{OUT} | -0.5 to V _{CC} +0.5 | V |
| Input diode current | I _{IK} | ±20 | mA |
| Output diode current | I _{OK} | ±20 | mA |
| Output current | I _{OUT} | ±25 | mA |
| V _{cc} /GND current | I _{CC} , I _{GND} | ±25 | mA |
| Power dissipation | P _T | 200 | mW |
| Strage temperature | Tstg | -65 to +150 | °C |

Recommended Operating Conditions

| Item | Symbol | Ratings | Unit |
|-----------------------|---------------------------------|---------------------------------------|------|
| Supply voltage | V _{cc} | 2 to 6 | V |
| Input voltage | V_{iN} | 0 to V_{cc} | V |
| Output voltage | V _{out} | 0 to V _{cc} | V |
| Operating temperature | Topr | -40 to +85 | °C |
| Input rise/fall time | t _r , t _f | 0 to 1000 (V _{cc} = 2.0 V) | ns |
| | | 0 to 500 ($V_{CC} = 4.5 \text{ V}$) | |
| | | 0 to 400 ($V_{CC} = 6.0 \text{ V}$) | |

Electrical Characteristics

| | | Ta = | 25°C | ; | Ta = - 85°C | -40 to | | Test Co | onditions | |
|-------------------|-----------------|------|------|------|----------------|--------|------|-----------------|--------------------------------------|----------------------------|
| Item | Symbol | Min | Тур | Max | Min | Max | Unit | V _{cc} | _ | |
| Input voltage | V_{IH} | 1.5 | _ | _ | 1.5 | _ | V | 2.0 | | |
| | | 3.15 | _ | _ | 3.15 | _ | _ | 4.5 | _ | |
| | | 4.2 | _ | _ | 4.2 | _ | | 6.0 | _ | |
| | V _{IL} | _ | _ | 0.5 | _ | 0.5 | V | 2.0 | | |
| | | _ | _ | 1.35 | _ | 1.35 | _ | 4.5 | _ | |
| | | _ | _ | 1.8 | _ | 1.8 | = | 6.0 | _ | |
| Output voltage | V _{OH} | 1.9 | 2.0 | _ | 1.9 | _ | V | 2.0 | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | $I_{OH} = -20 \mu A$ |
| | | 4.4 | 4.5 | _ | 4.4 | _ | _ | 4.5 | _ | |
| | | 5.9 | 6.0 | _ | 5.9 | _ | = | 6.0 | _ | |
| | | 4.18 | 4.31 | _ | 4.31 | _ | = | 4.5 | _ | $I_{OH} = -2 \text{ mA}$ |
| | | 5.68 | 5.80 | _ | 5.63 | _ | = | 6.0 | _ | $I_{OH} = -2.6 \text{ mA}$ |
| | V _{OL} | _ | 0.0 | 0.1 | _ | 0.1 | V | 2.0 | $V_{IN} = V_{IH}$ | I _{OL} = 20 μA |
| | | _ | 0.0 | 0.1 | _ | 0.1 | = | 4.5 | _ | |
| | | _ | 0.0 | 0.1 | _ | 0.1 | = | 6.0 | _ | |
| | | _ | 0.17 | 0.26 | _ | 0.33 | = | 4.5 | _ | I _{OL} = 2 mA |
| | | _ | 0.18 | 0.26 | _ | 0.33 | _ | 6.0 | = | I _{OL} = 2.6 mA |
| Input current | I _{IN} | _ | _ | ±0.1 | _ | ±1.0 | μΑ | 6.0 | $V_{IN} = V_{CC}$ or GN | ID |
| Operating current | I _{cc} | _ | _ | 1.0 | _ | 10.0 | _ | 6.0 | $V_{IN} = V_{CC}$ or GN | ID |

Switching Characteristics

| | | Ta = 2 | Ta = 25°C | | | |
|------------------------|-----------------------------|--------|-----------|-----|------|------------------------|
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
| Output rise/fall time | t _{TLH} | _ | 5 | 10 | ns | See Test circuit |
| | t_{THL} | | | | | |
| Propagation delay time | t _{PLH} | _ | 7 | 15 | ns | See Test circuit |
| | $t_{\scriptscriptstylePHL}$ | | | | | |

 $(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$

HD74UH00

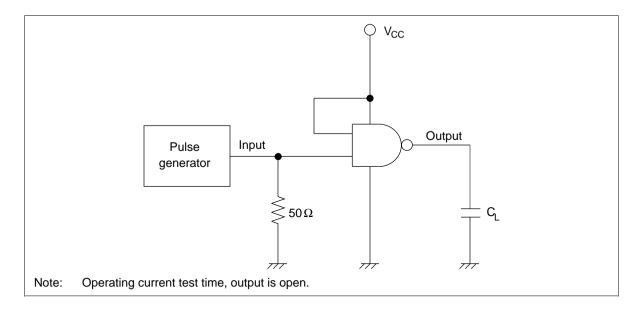
| | | Ta = 25°C | | Ta = −40 to 85°C | | | Test Conditions | | |
|------------------------|------------------|-----------|-----|---------------------|-----|-----|-----------------|-----------------|------------------|
| Item | Symbol | Min | Тур | Max | Min | Max | Unit | V _{cc} | _ |
| Output rise/fall time | t _{TLH} | _ | 50 | 125 | _ | 155 | ns | 2.0 | See under figure |
| | t_{THL} | _ | 14 | 25 | _ | 31 | | 4.5 | |
| | | _ | 12 | 21 | _ | 26 | _ | 6.0 | |
| Propagation delay time | t _{PLH} | _ | 48 | 100 | _ | 125 | ns | 2.0 | See under figure |
| | $t_{\tiny PHL}$ | _ | 12 | 20 | _ | 25 | - | 4.5 | |
| | | _ | 9 | 17 | _ | 21 | - | 6.0 | |
| Input capacitance | C _{IN} | _ | 5 | 10 | _ | 10 | pF | _ | |
| Equivalent capacitance | C_{PD} | _ | 10 | _ | _ | _ | <u> </u> | _ | |

 $(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$

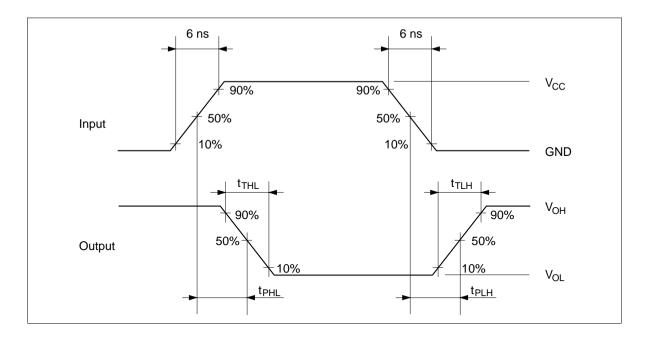
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

 $I_{cc}(opr) = C_{PD} \cdot V_{cc} \cdot f_{IN} + I_{cc}$

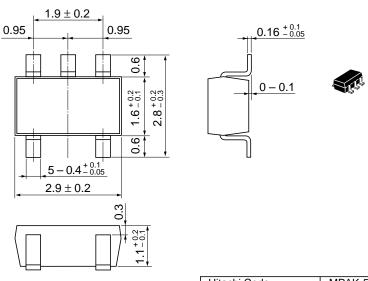
Test Circuit



Waveforms



Unit: mm



| Hitachi Code | MPAK-5 |
|--------------------------|---------|
| JEDEC | |
| EIAJ | |
| Weight (reference value) | 0.015 g |

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